



# MCP6001/2/4

## 1.0 ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings †

$V_{DD} - V_{SS}$ .....	7.0V
All Inputs and Outputs .....	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V$
Difference Input Voltage .....	$ V_{DD} - V_{SS} $
Output Short Circuit Current .....	continuous
Current at Input Pins .....	$\pm 2$ mA
Current at Output and Supply Pins .....	$\pm 30$ mA
Storage Temperature .....	$-65^{\circ}\text{C}$ to $+150^{\circ}\text{C}$
Maximum Junction Temperature ( $T_J$ ) .....	$+150^{\circ}\text{C}$
ESD Protection On All Pins (HBM;MM) .....	$\geq 4$ kV; 200V

† **Notice:** Stresses above those listed under “Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

## PIN FUNCTION TABLE

Name	Function
$V_{IN}^+$ , $V_{INA}^+$ , $V_{INB}^+$ , $V_{INC}^+$ , $V_{IND}^+$	Non-inverting Inputs
$V_{IN}^-$ , $V_{INA}^-$ , $V_{INB}^-$ , $V_{INC}^-$ , $V_{IND}^-$	Inverting Inputs
$V_{DD}$	Positive Power Supply
$V_{SS}$	Negative Power Supply
$V_{OUT}$ , $V_{OUTA}$ , $V_{OUTB}$ , $V_{OUTC}$ , $V_{OUTD}$	Outputs

## DC ELECTRICAL SPECIFICATIONS

**Electrical Characteristics:** Unless otherwise indicated,  $T_A = +25^{\circ}\text{C}$ ,  $V_{DD} = +1.8V$  to  $+5.5V$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $R_L = 10$  k $\Omega$  to  $V_{DD}/2$ , and  $V_{OUT} \sim V_{DD}/2$ .

Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Input Offset</b>						
Input Offset Voltage	$V_{OS}$	-7.0	—	+7.0	mV	$V_{CM} = V_{SS}$
Input Offset Drift with Temperature	$\Delta V_{OS}/\Delta T_A$	—	$\pm 2.0$	—	$\mu\text{V}/^{\circ}\text{C}$	$T_A = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ , $V_{CM} = V_{SS}$
Power Supply Rejection	PSRR	—	86	—	dB	$V_{CM} = V_{SS}$
<b>Input Bias Current and Impedance</b>						
Input Bias Current:	$I_B$	—	$\pm 1.0$	—	pA	
Industrial Temperature	$I_B$	—	19	—	pA	$T_A = +85^{\circ}\text{C}$
Extended Temperature	$I_B$	—	1100	—	pA	$T_A = +125^{\circ}\text{C}$
Input Offset Current	$I_{OS}$	—	$\pm 1.0$	—	pA	
Common Mode Input Impedance	$Z_{CM}$	—	$10^{13}  6$	—	$\Omega  \text{pF}$	
Differential Input Impedance	$Z_{DIFF}$	—	$10^{13}  3$	—	$\Omega  \text{pF}$	
<b>Common Mode</b>						
Common Mode Input Range	$V_{CMR}$	$V_{SS} - 0.3$	—	$V_{DD} + 0.3$	V	
Common Mode Rejection Ratio	CMRR	60	76	—	dB	$V_{CM} = -0.3V$ to $5.3V$ , $V_{DD} = 5V$
<b>Open-Loop Gain</b>						
DC Open-Loop Gain (large signal)	$A_{OL}$	88	112	—	dB	$V_{OUT} = 0.3V$ to $V_{DD} - 0.3V$ , $V_{CM} = V_{SS}$
<b>Output</b>						
Maximum Output Voltage Swing	$V_{OL}$ , $V_{OH}$	$V_{SS} + 25$	—	$V_{DD} - 25$	mV	$V_{DD} = 5.5V$
Output Short-Circuit Current	$I_{SC}$	—	$\pm 6$	—	mA	$V_{DD} = 1.8V$
		—	$\pm 23$	—	mA	$V_{DD} = 5.5V$
<b>Power Supply</b>						
Supply Voltage	$V_{DD}$	1.8	—	5.5	V	
Quiescent Current per Amplifier	$I_Q$	50	100	170	$\mu\text{A}$	$I_O = 0$ , $V_{DD} = 5.5V$ , $V_{CM} = 5V$

## AC ELECTRICAL SPECIFICATIONS

**Electrical Characteristics:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8$  to  $5.5\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_{DD}/2$ , and  $C_L = 60\text{ pF}$ .

Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>AC Response</b>						
Gain Bandwidth Product	GBWP	—	1.0	—	MHz	
Phase Margin	PM	—	90	—	°	G = +1
Slew Rate	SR	—	0.6	—	V/ $\mu\text{s}$	
<b>Noise</b>						
Input Noise Voltage	$E_{ni}$	—	6.1	—	$\mu\text{Vp-p}$	f = 0.1 Hz to 10 Hz
Input Noise Voltage Density	$e_{ni}$	—	28	—	nV/ $\sqrt{\text{Hz}}$	f = 1 kHz
Input Noise Current Density	$i_{ni}$	—	0.6	—	fA/ $\sqrt{\text{Hz}}$	f = 1 kHz

## TEMPERATURE SPECIFICATIONS

**Electrical Characteristics:** Unless otherwise indicated,  $V_{DD} = +1.8\text{V}$  to  $+5.5\text{V}$ , and  $V_{SS} = \text{GND}$ .

Parameters	Sym	Min	Typ	Max	Units	Conditions
<b>Temperature Ranges</b>						
Industrial Temperature Range	$T_A$	-40	—	+85	°C	
Extended Temperature Range	$T_A$	-40	—	+125	°C	
Operating Temperature Range	$T_A$	-40	—	+125	°C	(Note)
Storage Temperature Range	$T_A$	-65	—	+150	°C	
<b>Thermal Package Resistances</b>						
Thermal Resistance, 5L-SC70	$\theta_{JA}$	—	331	—	°C/W	
Thermal Resistance, 5L-SOT-23	$\theta_{JA}$	—	256	—	°C/W	
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	—	85	—	°C/W	
Thermal Resistance, 8L-SOIC (150 mil)	$\theta_{JA}$	—	163	—	°C/W	
Thermal Resistance, 8L-SOIC (208 mil)	$\theta_{JA}$	—	118	—	°C/W	
Thermal Resistance, 8L-MSOP	$\theta_{JA}$	—	206	—	°C/W	
Thermal Resistance, 14L-PDIP	$\theta_{JA}$	—	70	—	°C/W	
Thermal Resistance, 14L-SOIC	$\theta_{JA}$	—	120	—	°C/W	
Thermal Resistance, 14L-TSSOP	$\theta_{JA}$	—	100	—	°C/W	

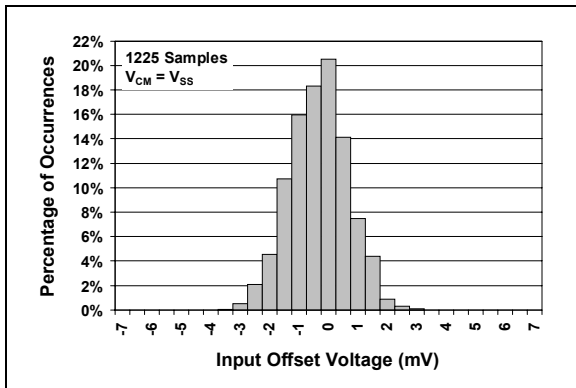
**Note:** The industrial temperature devices operate over this extended temperature range, but with reduced performance. In any case, the internal Junction Temperature ( $T_J$ ) must not exceed the Absolute Maximum specification of  $+150^\circ\text{C}$ .

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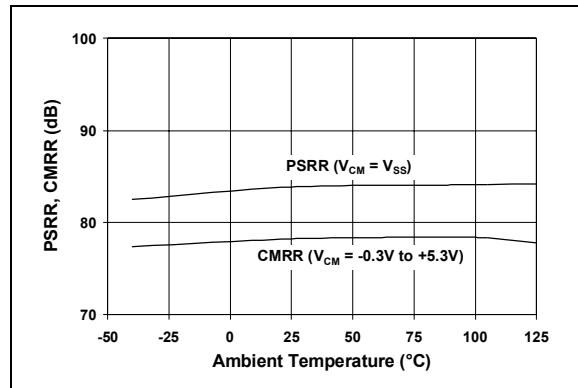
## 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

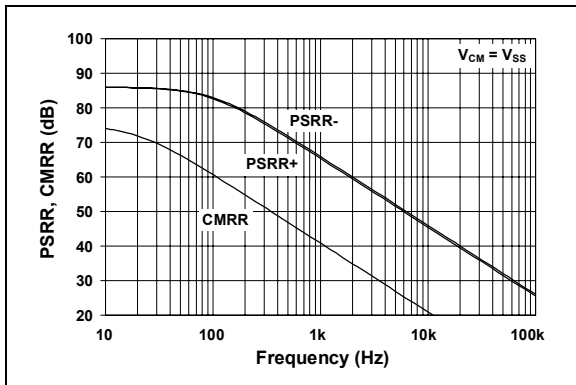
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V to } +5.5\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_{DD}/2$ , and  $C_L = 60\text{ pF}$ .



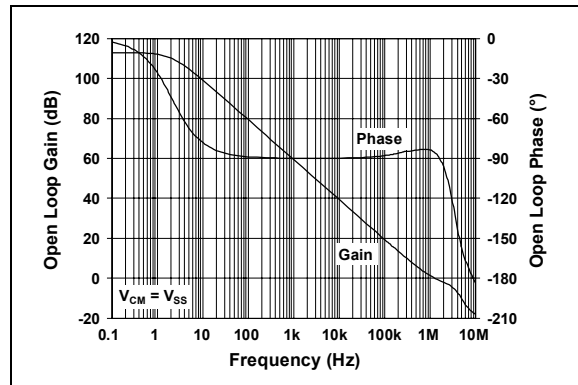
**FIGURE 2-1:** Input Offset Voltage Histogram.



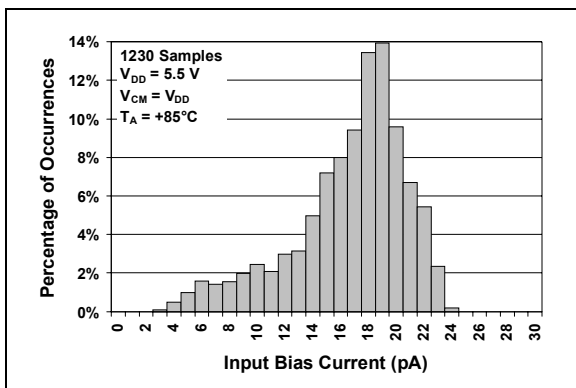
**FIGURE 2-4:** CMRR, PSRR vs. Ambient Temperature.



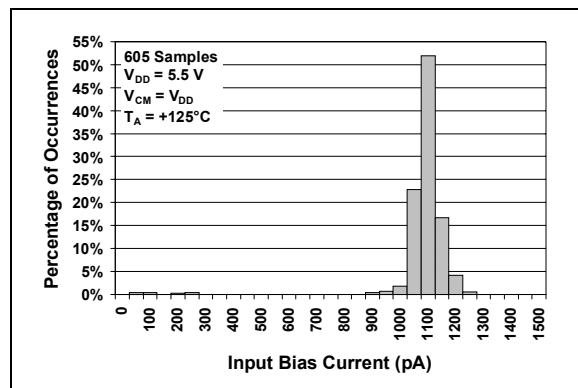
**FIGURE 2-2:** PSRR, CMRR vs. Frequency.



**FIGURE 2-5:** Open-Loop Gain, Phase vs. Frequency.

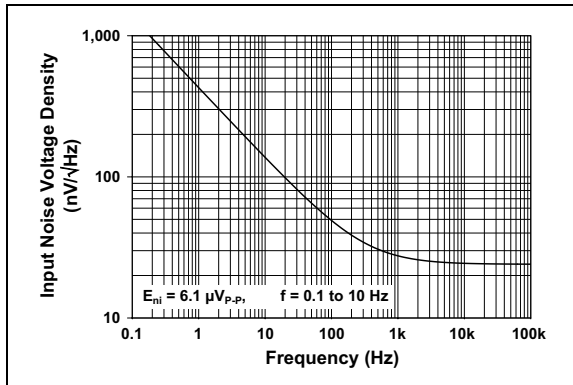


**FIGURE 2-3:** Input Bias Current at  $+85^\circ\text{C}$  Histogram.

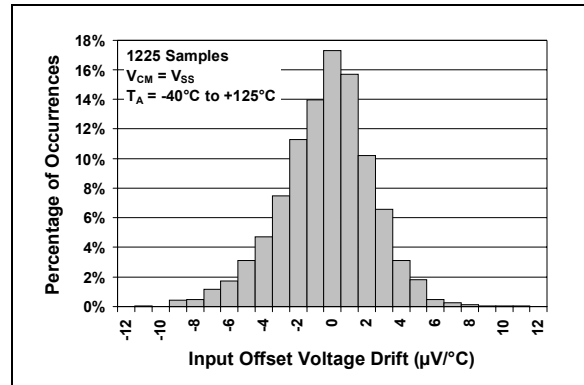


**FIGURE 2-6:** Input Bias Current at  $+125^\circ\text{C}$  Histogram.

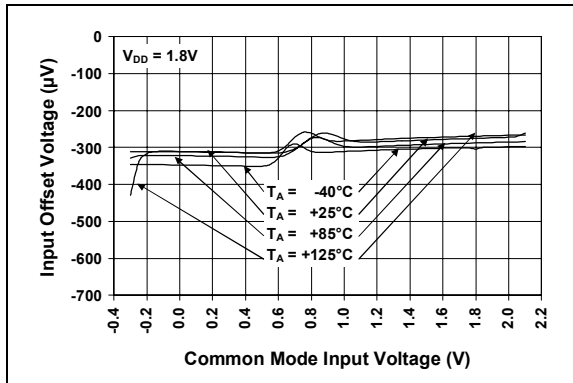
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+5.5\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_{DD}/2$ , and  $C_L = 60\text{ pF}$ .



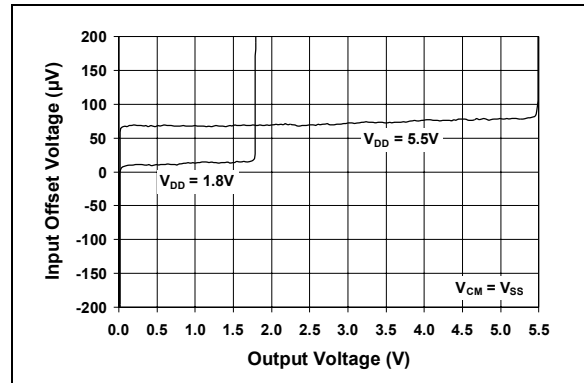
**FIGURE 2-7:** Input Noise Voltage Density vs. Frequency.



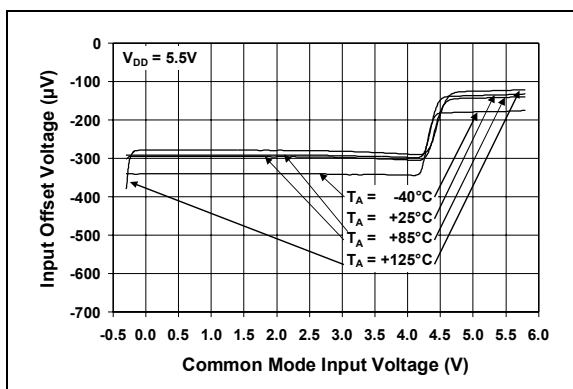
**FIGURE 2-10:** Input Offset Voltage Drift Histogram.



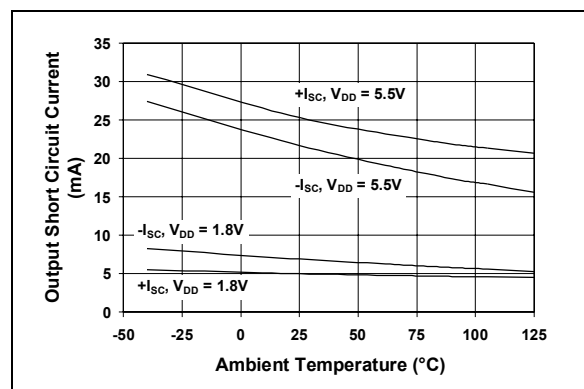
**FIGURE 2-8:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 1.8\text{V}$ .



**FIGURE 2-11:** Input Offset Voltage vs. Output Voltage.



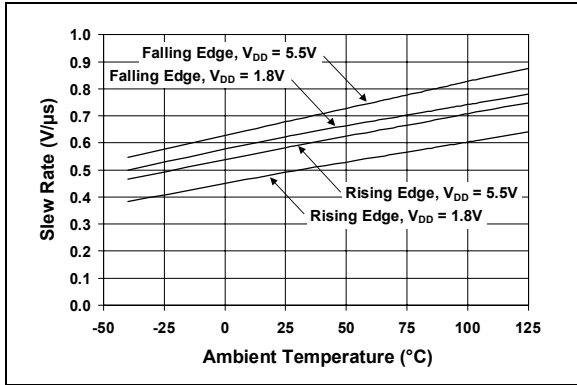
**FIGURE 2-9:** Input Offset Voltage vs. Common Mode Input Voltage at  $V_{DD} = 5.5\text{V}$ .



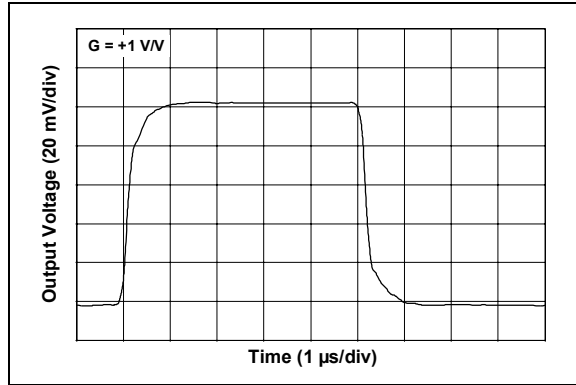
**FIGURE 2-12:** Output Short-Circuit Current vs. Ambient Temperature.

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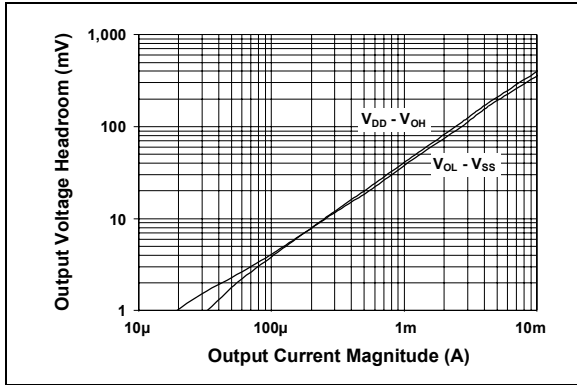
**Note:** Unless otherwise indicated,  $T_A = +25^\circ\text{C}$ ,  $V_{DD} = +1.8\text{V}$  to  $+5.5\text{V}$ ,  $V_{SS} = \text{GND}$ ,  $V_{CM} = V_{DD}/2$ ,  $V_{OUT} \approx V_{DD}/2$ ,  $R_L = 10\text{ k}\Omega$  to  $V_{DD}/2$ , and  $C_L = 60\text{ pF}$ .



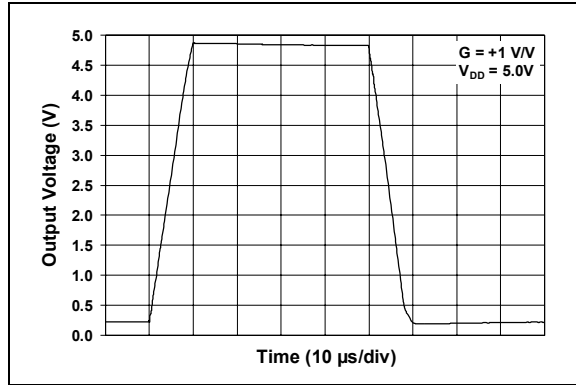
**FIGURE 2-13:** Slew Rate vs. Ambient Temperature.



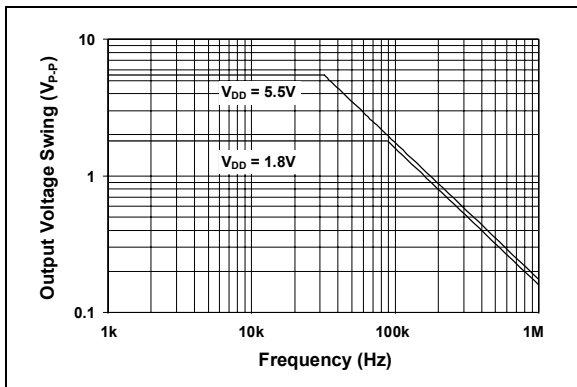
**FIGURE 2-16:** Small Signal Non-Inverting Pulse Response.



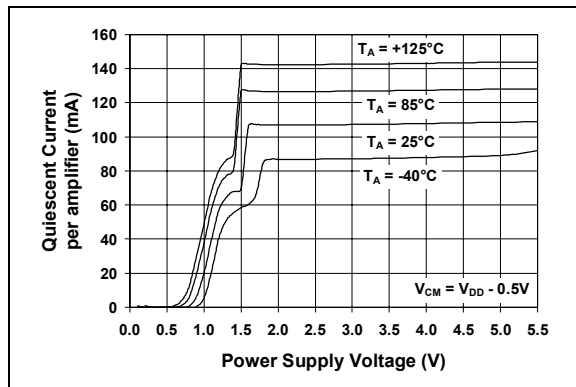
**FIGURE 2-14:** Output Voltage Headroom vs. Output Current Magnitude.



**FIGURE 2-17:** Large Signal Non-Inverting Pulse Response.



**FIGURE 2-15:** Output Voltage Swing vs. Frequency.



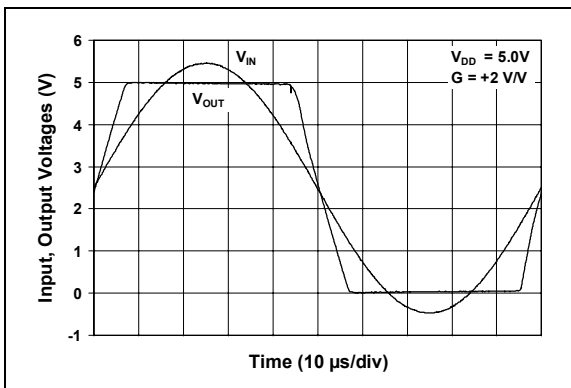
**FIGURE 2-18:** Quiescent Current vs. Power Supply Voltage.

## 3.0 APPLICATION INFORMATION

The MCP6001/2/4 family of op amps is manufactured using Microchip's state-of-the-art CMOS process and is specifically designed for low cost, low power and general-purpose applications. The low supply voltage, low quiescent current and wide bandwidth makes the MCP6001/2/4 ideal for battery-powered applications. This device has high phase margin, which makes it stable for larger capacitive load applications.

### 3.1 Rail-to-Rail Input

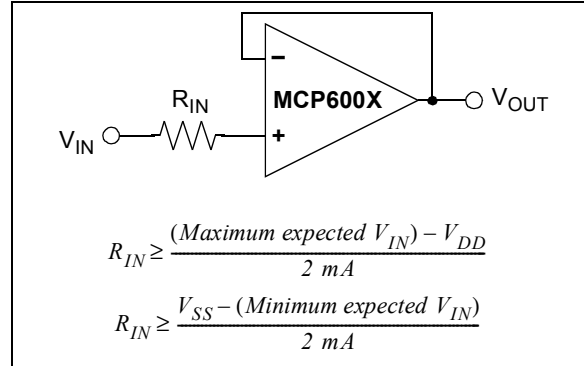
The MCP6001/2/4 op amp is designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 3-1 shows the input voltage exceeding the supply voltage without any phase reversal.



**FIGURE 3-1:** The MCP6001/2/4 Shows No Phase Reversal.

The input stage of the MCP6001/2/4 op amp uses two differential input stages in parallel; one operates at low common mode input voltage ( $V_{CM}$ ) and the other at high  $V_{CM}$ . With this topology, the device operates with  $V_{CM}$  up to 300 mV above  $V_{DD}$  and 300 mV below  $V_{SS}$ . The Input Offset Voltage is measured at  $V_{CM} = V_{SS} - 300$  mV and  $V_{DD} + 300$  mV to ensure proper operation.

Input voltages that exceed the input voltage range ( $V_{SS} - 0.3$ V to  $V_{DD} + 0.3$ V at 25°C) can cause excessive current to flow into or out of the input pins. Current beyond  $\pm 2$  mA can cause reliability problems. Applications that exceed this rating must be externally limited with a resistor, as shown in Figure 3-2.



**FIGURE 3-2:** Input Current Limiting Resistor ( $R_{IN}$ ).

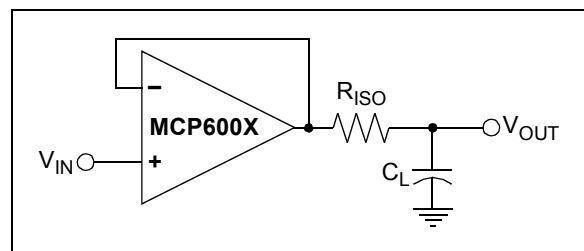
### 3.2 Rail-to-Rail Output

The output voltage range of the MCP6001/2/4 op amp is  $V_{DD} - 25$  mV (min.) and  $V_{SS} + 25$  mV (max.) when  $R_L = 10$  k $\Omega$  is connected to  $V_{DD}/2$  and  $V_{DD} = 5.5$ V. Refer to Figure 2-14 for more information.

### 3.3 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases, and the closed loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer ( $G = +1$ ) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g.,  $> 100$  pF when  $G = +1$ ), a small series resistor at the output ( $R_{ISO}$  in Figure 3-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. It does not, however, improve the bandwidth.



**FIGURE 3-3:** Output resistor,  $R_{ISO}$  stabilizes large capacitive loads.

To select  $R_{ISO}$ , check the frequency response peaking (or step response overshoot) on the bench (or with the MCP6001/2/4 Spice macro model). If the response is reasonable, you do not need  $R_{ISO}$ . Otherwise, start  $R_{ISO}$  at 1 k $\Omega$  and modify its value until the response is reasonable.

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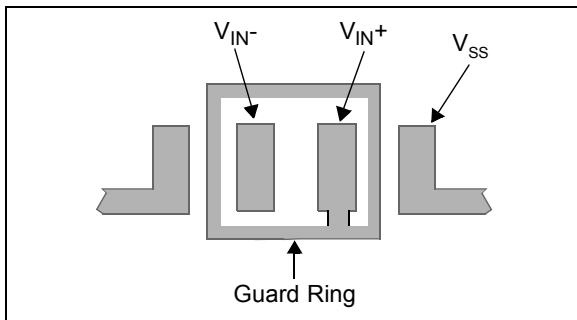
## 3.4 Supply Bypass

With this family of operation amplifiers, the power supply pin ( $V_{DD}$  for single supply) should have a local bypass capacitor (i.e., 0.01  $\mu\text{F}$  to 0.1  $\mu\text{F}$ ) within 2 mm for good high frequency performance. It also needs a bulk capacitor (i.e., 1  $\mu\text{F}$  or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other parts.

## 3.5 PCB Surface Leakage

In applications where low input bias current is critical, PCB (printed circuit board) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is  $10^{12}\Omega$ . A 5V difference would cause 5 pA, if current-to-flow; this is greater than the MCP6001/2/4 family's bias current at 25°C (1 pA, typ).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 3-4.



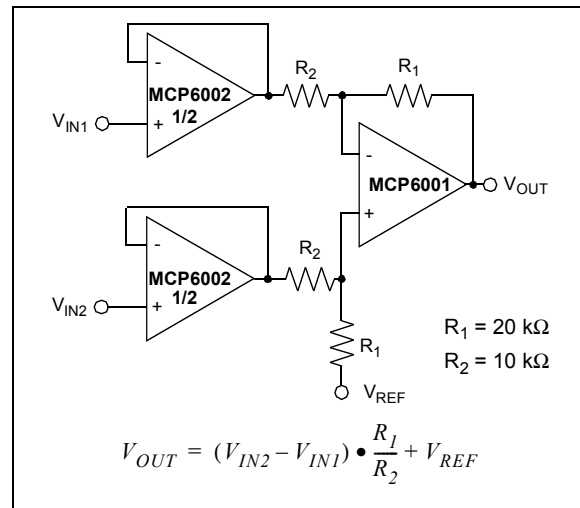
**FIGURE 3-4:** Example Guard Ring Layout for Inverting Gain.

1. Non-inverting Gain and Unity Gain Buffer:
  - a. Connect the non-inverting pin ( $V_{IN+}$ ) to the input with a wire that does not touch the pcb surface.
  - b. Connect the guard ring to the inverting input pin ( $V_{IN-}$ ). This biases the guard ring to the common mode input voltage.
2. Inverting and Transimpedance Gain Amplifiers (convert current to voltage, such as photo detectors):
  - a. Connect the guard ring to the non-inverting input pin ( $V_{IN+}$ ). This biases the guard ring to the same reference voltage as the op amp (e.g.,  $V_{DD}/2$  or ground).
  - b. Connect the inverting pin ( $V_{IN-}$ ) to the input with a wire that does not touch the PCB surface.

## 3.6 Application Circuits

### 3.6.1 UNITY GAIN BUFFER

The rail-to-rail input and output capability of the MCP6001/2/4 op amp is ideal for unity-gain buffer applications. The low quiescent current and wide bandwidth makes the device suitable for a buffer configuration in an instrumentation amplifier circuit, as shown in Figure 3-5.



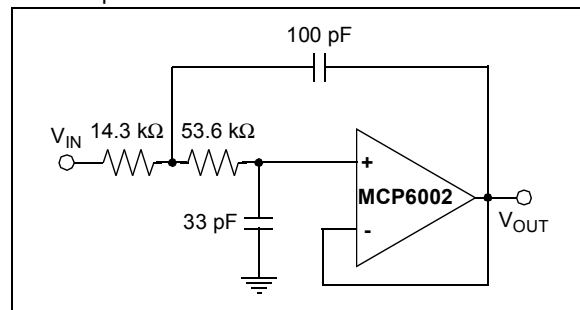
**FIGURE 3-5:** Instrumentation Amplifier with Unity Gain Buffer Inputs.

### 3.6.2 ACTIVE LOW-PASS FILTER

The MCP6001/2/4 op amp's low input bias current makes it possible for the designer to use larger resistors and smaller capacitors for active low-pass filter applications. However, as the resistance increases, the noise generated also increases. Parasitic capacitances and the large value resistors could also modify the frequency response. These trade-offs need to be considered when selecting circuit elements.

It is possible to have a filter cutoff frequency as high as 1/10th of the op amp bandwidth (100 kHz). Figure 3-6 shows a second-order butterworth filter with 100 kHz cutoff frequency and a gain of +1V/V.

The component values were selected using Microchip's FilterLab<sup>®</sup> software.



**FIGURE 3-6:** Active Second-Order Low-Pass Filter.



### 3.6.3 PEAK DETECTOR

The MCP6001/2/4 op amp has a high input impedance, rail-to-rail input and output and low input bias current, which makes this device suitable for a peak detector applications. Figure 3-7 shows a peak detector circuit with clear and sample switches. The peak-detection cycle uses a clock (CLK), as shown in Figure 3-7.

At the rising edge of CLK, Sample Switch closes to begin sampling. The peak voltage stored on  $C_1$  is sampled to  $C_2$  for a sample time defined by  $t_{SAMP}$ . At the end of the sample time (falling edge of Sample Signal), Clear Signal goes high and closes the Clear Switch. When the Clear Switch closes,  $C_1$  discharges through  $R_1$  for a time defined by  $t_{CLEAR}$ . At the end of the clear time (falling edge of Clear Signal), op amp A begins to store the peak value of  $V_{IN}$  on  $C_1$  for a time defined by  $t_{DETECT}$ .

In order to define the  $t_{SAMP}$  and  $t_{CLEAR}$ , it is necessary to determine the capacitor charging and discharging period. The capacitor charging time is limited by the amplifier source current, while the discharging time ( $\tau$ ) is defined using  $R_1$  ( $\tau = R_1 * C_1$ ).  $t_{DETECT}$  is the time that the input signal is sampled on  $C_1$ , and is dependent on the input voltage change frequency.

The op amp output current limit, and the size of the storage capacitors (both  $C_1$  and  $C_2$ ), could create slewing limitations as the input voltage ( $V_{IN}$ ) increases. Current through a capacitor is dependent on the size of the capacitor and the rate of voltage change. From this relationship, the rate of voltage change or the slew rate

can be determined. For example, with op amp short-circuit current of  $I_{SC} = 25 \text{ mA}$  and load capacitor of  $C_1 = 0.1 \mu\text{F}$ , then:

#### EQUATION

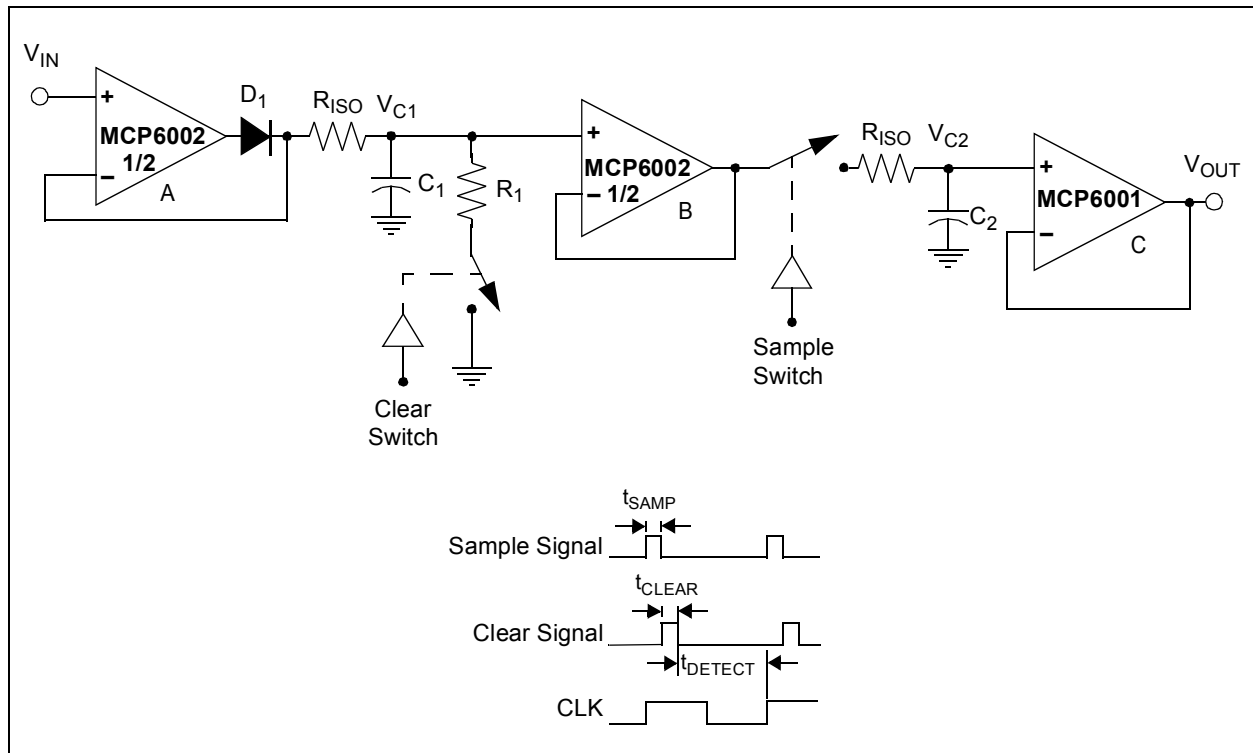
$$I_{SC} = C_1 \times \frac{dV_{C1}}{dt}$$

$$\frac{dV_{C1}}{dt} = \frac{I_{SC}}{C_1}$$

$$= \frac{25 \text{ mA}}{0.1 \mu\text{F}}$$

$$\frac{dV_{C1}}{dt} = \frac{250 \text{ mV}}{\mu\text{s}}$$

This voltage change rate is less than the MCP6001/2/4 slew rate of  $600 \text{ mV}/\mu\text{s}$ . When the input voltage swings below the voltage across  $C_1$ ,  $D_1$  becomes reverse-biased, which opens the feedback loop and rails the amplifier. When the input voltage increases, the amplifier recovers at its slew rate. Based on the rate of voltage change shown in the above equation, it takes an extended period of time to charge a  $0.1 \mu\text{F}$  capacitor. The capacitors need to be selected so that the circuit is not limited by the amplifier slew rate. Therefore, the capacitors should be less than  $40 \mu\text{F}$  and a stabilizing resistor ( $R_{ISO}$ ) needs to be properly selected. Refer to Section 3.3, "Capacitive Load and Stability", for op amp stability.



**FIGURE 3-7:** Peak Detector with Clear and Sample CMOS Analog Switches.

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## 4.0 DESIGN TOOLS

Microchip provides the basic design tools needed for the MCP6001/2/4 family of op amps.

### 4.1 SPICE Macro Model

The latest Spice macro model for the MCP6001/2/4 operational amplifiers (op amps) is available on our website at [www.microchip.com](http://www.microchip.com). This model is intended as an initial design tool that works well in the op amp's linear region of operation at room temperature. See the model file for information on its capabilities.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

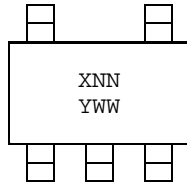
### 4.2 FilterLab<sup>®</sup> Software

FilterLab is an innovative software tool that simplifies analog active filter (using op amps) design. Available at no cost from our website at [www.microchip.com](http://www.microchip.com), the FilterLab software active filter software design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

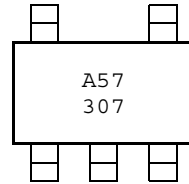
## 5.0 PACKAGING INFORMATION

### 5.1 Package Marking Information

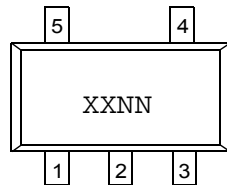
5-Lead SC-70 (MCP6001)



Example:

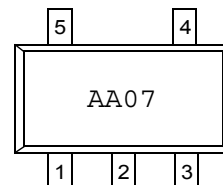


5-Lead SOT-23 (MCP6001)



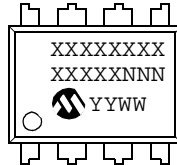
Device	Industrial Temp Code	Extended Temp Code
MCP6001	AANN	CDNN
MCP6001R	ADNN	CENN
MCP6001U	AFNN	CFNN

Example:(MCP6001 I-Temp Pinout)

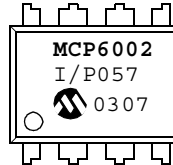


**Note:** Applies to 5-Lead SOT-23.

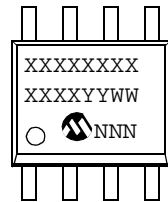
8-Lead PDIP (300 mil)



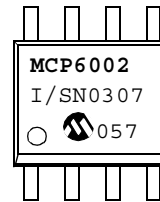
Example:



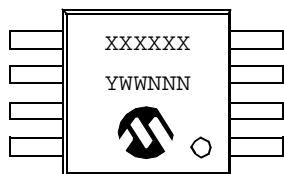
8-Lead SOIC (150 mil)



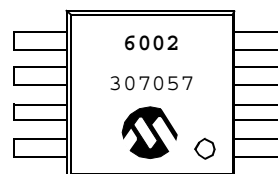
Example:



8-Lead MSOP



Example:



**Legend:** XX...X Customer specific information\*  
 YY Year code (last 2 digits of calendar year)  
 WW Week code (week of January 1 is week '01')  
 NNN Alphanumeric traceability code

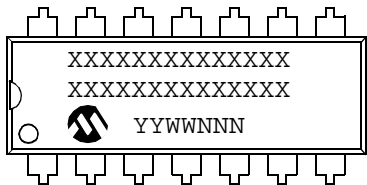
**Note:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line thus limiting the number of available characters for customer specific information.

\* Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

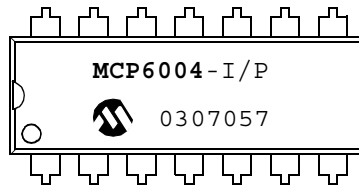
# MCP6001/2/4

## Package Marking Information (Continued)

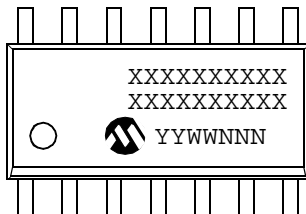
14-Lead PDIP (300 mil) (MCP6004)



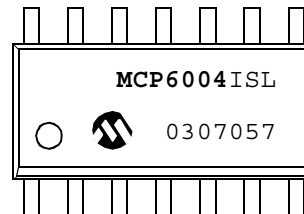
Example:



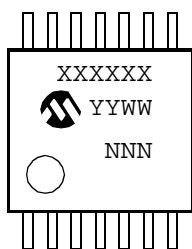
14-Lead SOIC (150 mil) (MCP6004)



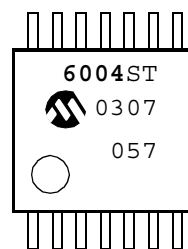
Example:



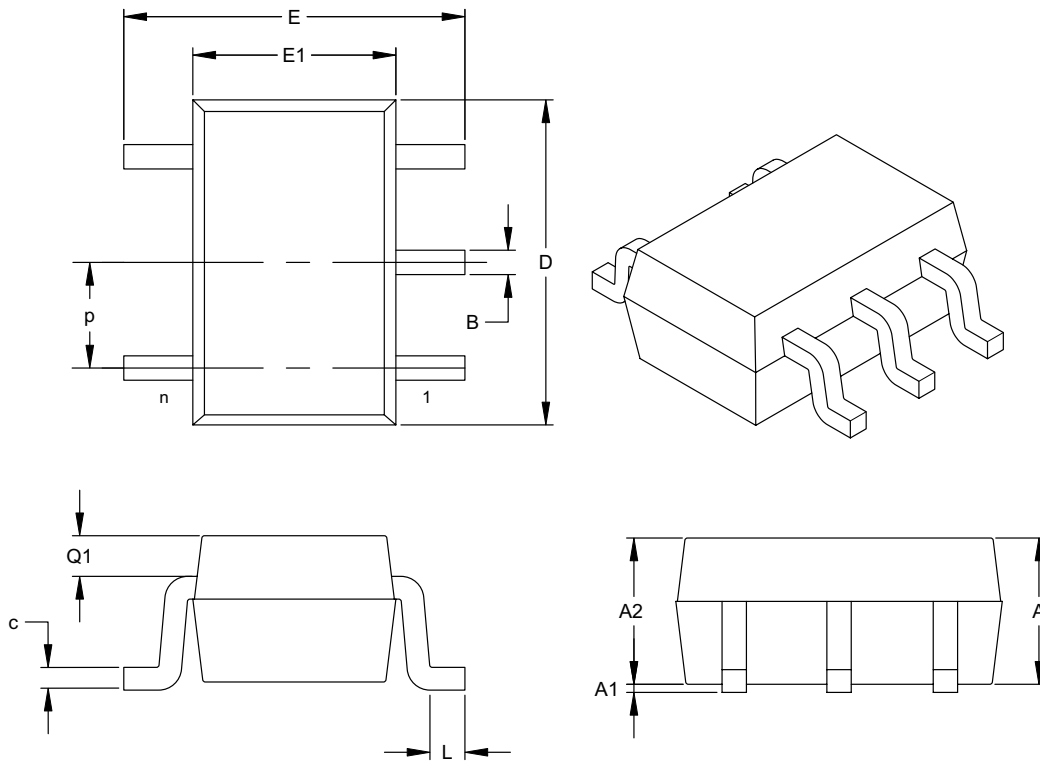
14-Lead TSSOP (MCP6004)



Example:



## 5-Lead Plastic Package (SC-70)



Dimension	Units	INCHES			MILLIMETERS*		
		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n	5			5		
Pitch	p	.026 (BSC)			0.65 (BSC)		
Overall Height	A	.031		.043	0.80		1.10
Molded Package Thickness	A2	.031		.039	0.80		1.00
Standoff	A1	.000		.004	0.00		0.10
Overall Width	E	.071		.094	1.80		2.40
Molded Package Width	E1	.045		.053	1.15		1.35
Overall Length	D	.071		.087	1.80		2.20
Foot Length	L	.004		.012	0.10		0.30
Top of Molded Pkg to Lead Shoulder	Q1	.004		.016	0.10		0.40
Lead Thickness	c	.004		.007	0.10		0.18
Lead Width	B	.006		.012	0.15		0.30

\*Controlling Parameter

Notes:

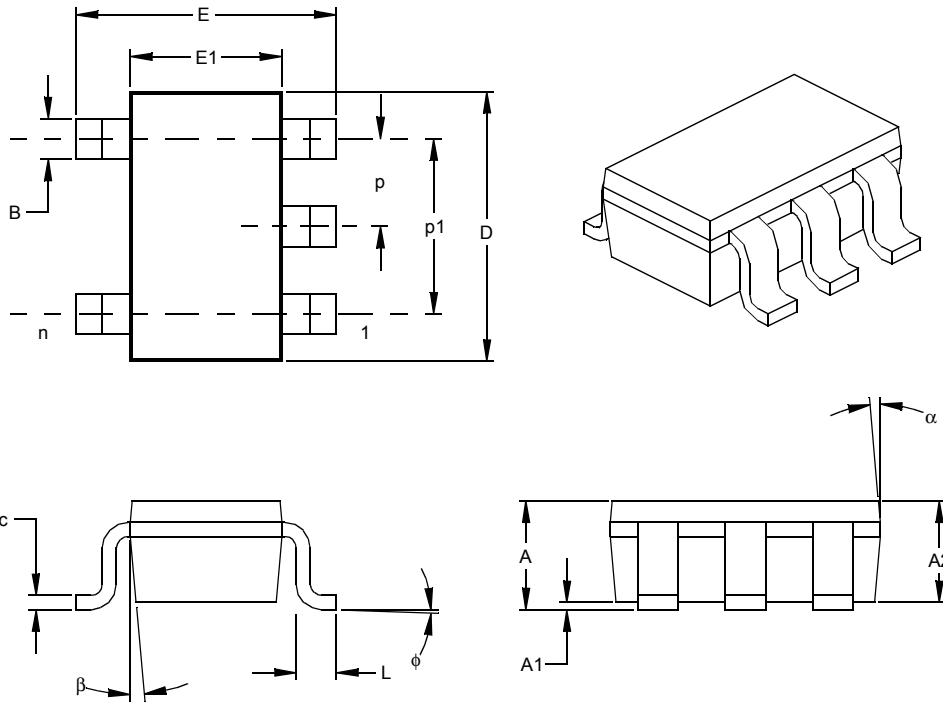
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (EIAJ) Standard: SC-70

Drawing No. C04-061

# MCP6001/2/4

## 5-Lead Plastic Small Outline Transistor (OT) (SOT23)



Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		5			5	
Pitch	p		.038			0.95	
Outside lead pitch (basic)	p1		.075			1.90	
Overall Height	A	.035	.046	.057	0.90	1.18	1.45
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30
Standoff §	A1	.000	.003	.006	0.00	0.08	0.15
Overall Width	E	.102	.110	.118	2.60	2.80	3.00
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75
Overall Length	D	.110	.116	.122	2.80	2.95	3.10
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	φ	0	5	10	0	5	10
Lead Thickness	c	.004	.006	.008	0.09	0.15	0.20
Lead Width	B	.014	.017	.020	0.35	0.43	0.50
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter  
 § Significant Characteristic

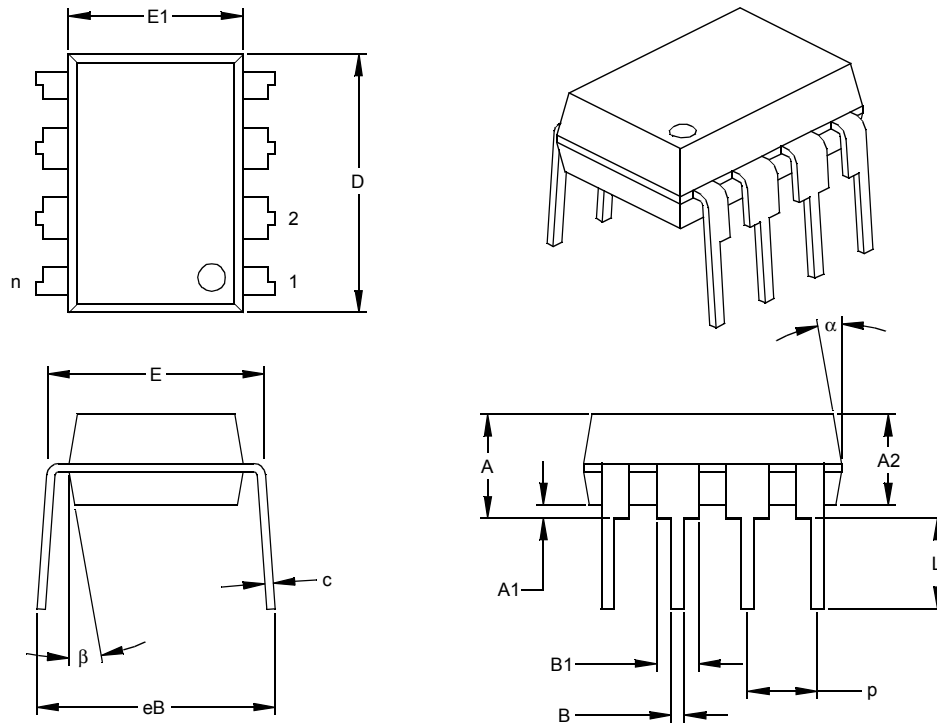
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-178

Drawing No. C04-091

## 8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)



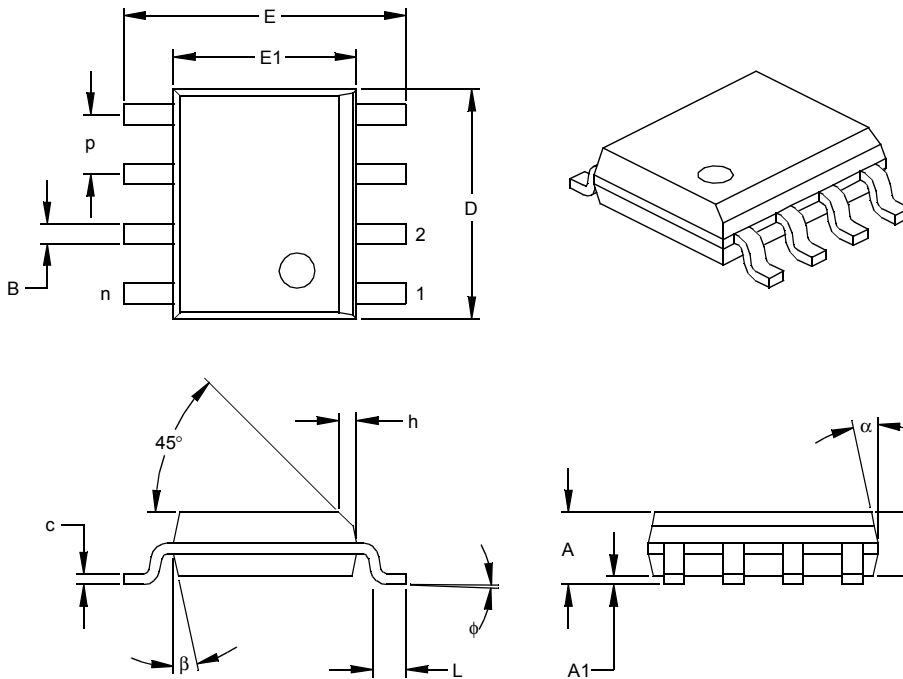
Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	p		.100			2.54	
Top to Seating Plane	A	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	c	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	B	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

\* Controlling Parameter  
 § Significant Characteristic

Notes:  
 Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.  
 JEDEC Equivalent: MS-001  
 Drawing No. C04-018

# MCP6001/2/4

## 8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)



Dimension Limits	Units	INCHES*			MILLIMETERS		
		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	p		.050			1.27	
Overall Height	A	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	c	.008	.009	.010	0.20	0.23	0.25
Lead Width	B	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

\* Controlling Parameter

§ Significant Characteristic

**Notes:**

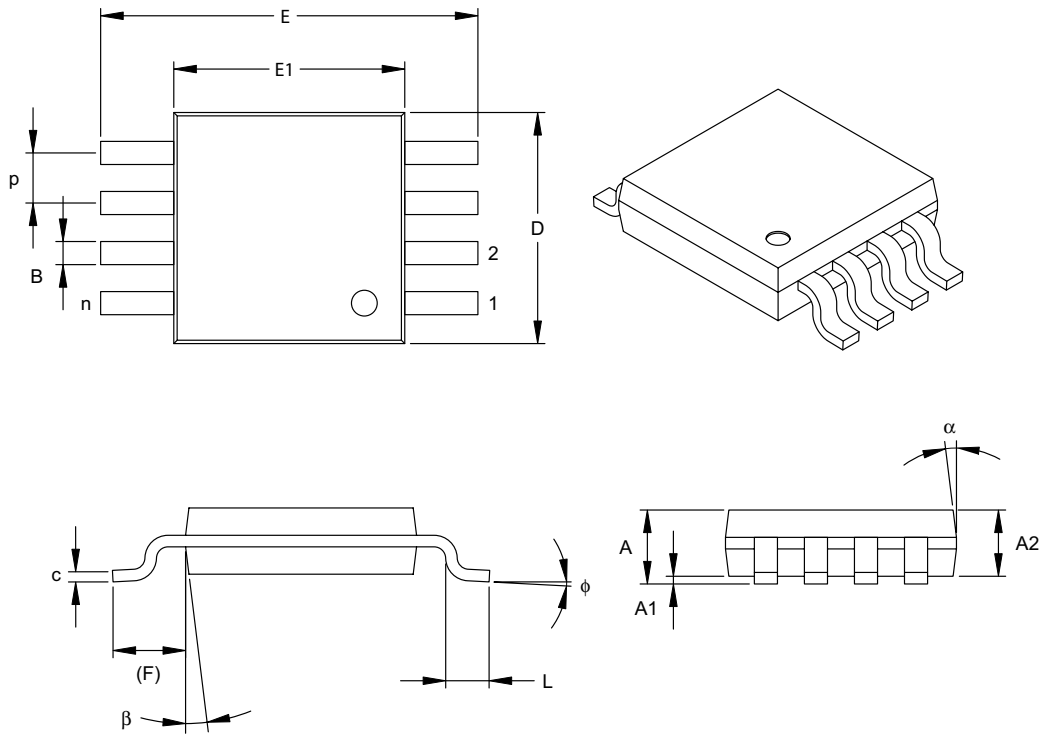
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012

Drawing No. C04-057



## 8-Lead Plastic Micro Small Outline Package (MS) (MSOP)



Dimension Limits	Units	INCHES			MILLIMETERS*		
		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	p	.026 BSC			0.65 BSC		
Overall Height	A	-	-	.043	-	-	1.10
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95
Standoff	A1	.000	-	.006	0.00	-	0.15
Overall Width	E	.193 TYP.			4.90 BSC		
Molded Package Width	E1	.118 BSC			3.00 BSC		
Overall Length	D	.118 BSC			3.00 BSC		
Foot Length	L	.016	.024	.031	0.40	0.60	0.80
Footprint (Reference)	F	.037 REF			0.95 REF		
Foot Angle	φ	0°	-	8°	0°	-	8°
Lead Thickness	c	.003	.006	.009	0.08	-	0.23
Lead Width	B	.009	.012	.016	0.22	-	0.40
Mold Draft Angle Top	α	5°	-	15°	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°	5°	-	15°

\*Controlling Parameter

Notes:

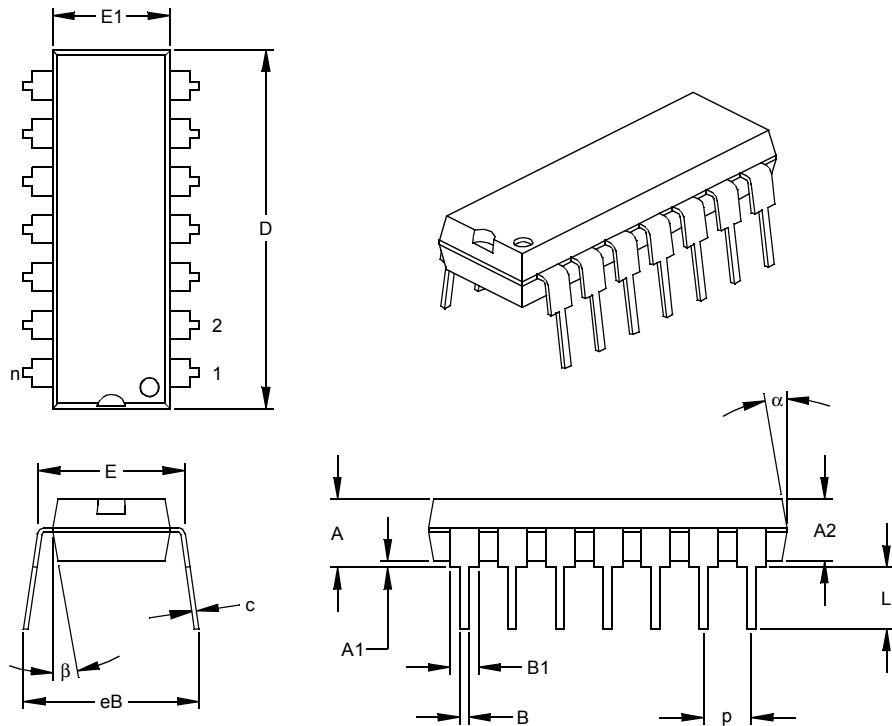
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MO-187

Drawing No. C04-111

# MCP6001/2/4

## 14-Lead Plastic Dual In-line (P) – 300 mil (PDIP)



Dimension Limits	Units	INCHES*			MILLIMETERS		
		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	p		.100			2.54	
Top to Seating Plane	A	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.740	.750	.760	18.80	19.05	19.30
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	c	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	B	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

\* Controlling Parameter

§ Significant Characteristic

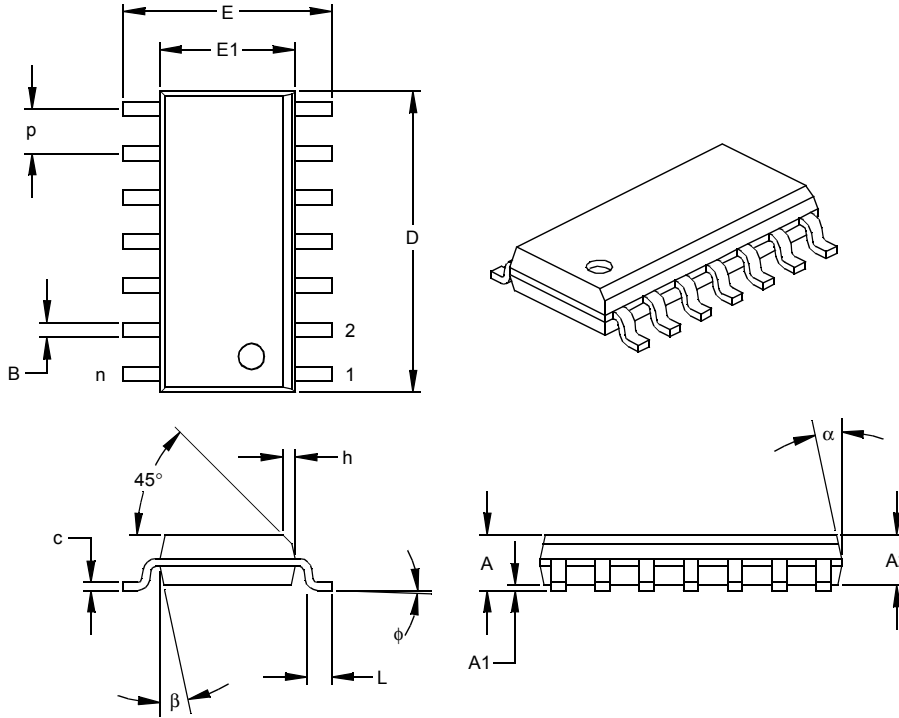
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-001

Drawing No. C04-005

## 14-Lead Plastic Small Outline (SL) – Narrow, 150 mil (SOIC)



Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	p		.050			1.27	
Overall Height	A	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	E	.228	.236	.244	5.79	5.99	6.20
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99
Overall Length	D	.337	.342	.347	8.56	8.69	8.81
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	c	.008	.009	.010	0.20	0.23	0.25
Lead Width	B	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

\* Controlling Parameter  
 § Significant Characteristic

Notes:

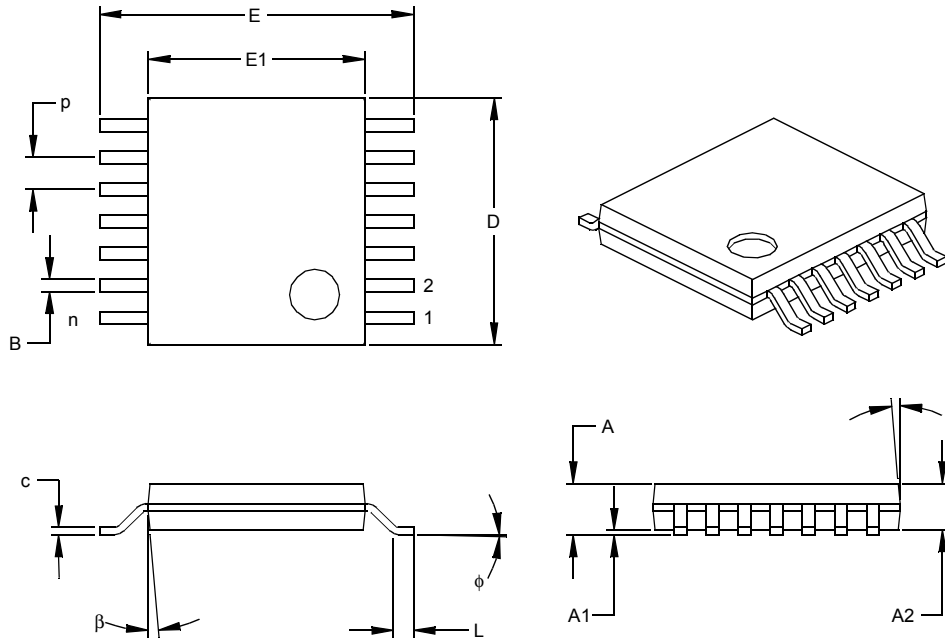
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-012

Drawing No. C04-065

# MCP6001/2/4

## 14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



Units		INCHES			MILLIMETERS*		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		14			14	
Pitch	p		.026			0.65	
Overall Height	A			.043			1.10
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15
Overall Width	E	.246	.251	.256	6.25	6.38	6.50
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10
Foot Length	L	.020	.024	.028	0.50	0.60	0.70
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	c	.004	.006	.008	0.09	0.15	0.20
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

\* Controlling Parameter  
 § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEDEC Equivalent: MO-153

Drawing No. C04-087

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>X</u>	<u>/XX</u>	
Device	Temperature Range	Package	
Device:	MCP6001T:	1 MHz Bandwidth, Low Power Op Amp (Tape and Reel) (SC-70, SOT-23)	
	MCP6001RT:	1 MHz Bandwidth, Low Power Op Amp (Tape and Reel) (SOT-23)	
	MCP6001UT:	1 MHz Bandwidth, Low Power Op Amp (Tape and Reel) (SOT-23)	
	MCP6002:	1 MHz Bandwidth, Low Power Op Amp	
	MCP6002T:	1 MHz Bandwidth, Low Power Op Amp (Tape and Reel) (SOIC, MSOP)	
	MCP6004:	1 MHz Bandwidth, Low Power Op Amp	
	MCP6004T:	1 MHz, Bandwidth Low Power Op Amp (Tape and Reel) (SOIC, MSOP)	
Temperature Range:	I = -40°C to +85°C		
	E = -40°C to +125°C		
Package:	LT = Plastic Package (SC-70), 5-lead (MCP6001 only)		
	OT = Plastic Small Outline Transistor (SOT-23), 5-lead (MCP6001, MCP6001R, MCP6001U)		
	MS = Plastic MSOP, 8-lead		
	P = Plastic DIP (300 mil Body), 8-lead, 14-lead		
	SN = Plastic SOIC, (150 mil Body), 8-lead		
	SL = Plastic SOIC (150 mil Body), 14-lead		
	ST = Plastic TSSOP (4.4mm Body), 14-lead		

<b>Examples:</b>	
a)	MCP6001T-I/LT: Tape and Reel, Industrial Temperature, 5LD SC-70 package
b)	MCP6001T-I/OT: Tape and Reel, Industrial Temperature, 5LD SOT-23 package.
c)	MCP6001RT-I/OT: Tape and Reel, Industrial Temperature, 5LD SOT-23 package.
d)	MCP6001UT-E/OT: Tape and Reel, Extended Temperature, 5LD SOT-23 package.
e)	MCP6001UT-I/OT: Tape and Reel, Industrial Temperature, 5LD SOT-23 package.
a)	MCP6002-I/MS: Industrial Temperature, 8LD MSOP package.
b)	MCP6002-I/P: Industrial Temperature, 8LD PDIP package.
c)	MCP6002-E/P: Extended Temperature, 8LD PDIP package.
d)	MCP6002-I/SN: Industrial Temperature, 8LD SOIC package.
e)	MCP6002T-I/MS: Tape and Reel, Industrial Temperature, 8LD MSOP package.
f)	MCP6002T-I/SN: Tape and Reel, Industrial Temperature, 8LD SOIC package.
a)	MCP6004-I/P: Industrial Temperature, 14LD PDIP package.
b)	MCP6004-I/SL: Industrial Temperature,, 14LD SOIC package.
c)	MCP6004-E/SL: Extended Temperature,, 14LD SOIC package.
d)	MCP6004-I/ST: Industrial Temperature, 14LD TSSOP package.
e)	MCP6004T-I/SL: Tape and Reel, Industrial Temperature, 14LD SOIC package.
f)	MCP6004T-I/ST: Tape and Reel, Industrial Temperature, 14LD TSSOP package.

## Sales and Support

### Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

1. Your local Microchip sales office
2. The Microchip Corporate Literature Center U.S. FAX: (480) 792-7277
3. The Microchip Worldwide Site ([www.microchip.com](http://www.microchip.com))

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

### Customer Notification System

Register on our web site ([www.microchip.com/cn](http://www.microchip.com/cn)) to receive the most current information on our products.

# MCP6001/2/4

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NOTES:

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**Note the following details of the code protection feature on Microchip devices:**

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

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